



- 1.
- 2. PDFN5060 TO-252 SOP8
- 3. $T_j(max) = 175$

MOSFET P60V
Qg Rdson
MOS EAS

1. It adopts advanced process technology, featuring low internal resistance and excellent switching characteristics;
2. It adopts PDFN5060, TO-252, SOP8 and o j ,

New Product Launch